



74AUP2G34
DUAL BUFFERS

Description

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

The 74AUP2G34 is composed of two buffers with standard push-pull outputs designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using $I_{\rm OFF}$. The $I_{\rm OFF}$ circuitry disables the output preventing damaging current backflow when the device is powered down. The gates perform the positive Boolean function:

Y = A

Pin Assignments

(Top View)







Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- ±4mA Output Drive at 3.0V
- Low Static power consumption
 - I_{CC} < 0.9µA
- Low Dynamic Power Consumption
 - C_{PD} = 6pF Typical at 3.6V
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time. The hysteresis is typically 250mV at V_{CC} = 3.0V
- I_{OFF} Supports Partial-Power-Down Mode Operation
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless packages per JESD30E
 - DFN1410 denoted as X2-DFN1410-6
 - DFN1010 denoted as X2-DFN1010-6
 - DFN0910 denoted as X2-DFN0910-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

- Suited for battery and low power needs
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Tablet Computers, E-readers
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Cell Phones, Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Click for Ordering Information

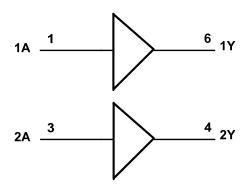
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Pin Descriptions

Pin Name	Pin No.	Function			
1A	1	Data Input			
GND	2	Ground			
2A	3	Data Input			
2Y	4	Data Output			
V _{CC}	5	Supply Voltage			
1Y	6	Data Output			

Logic Diagram



Function Table

Inputs	Outputs
Α	Y
Н	Н
L	L

Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +4.6	V
VI	Input Voltage Range	-0.5 to +4.6	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	50	mA
lok	Output Clamp Current (V _O < 0)	-50	mA
Io	Continuous Output Current (V _O = 0 to V _{CC})	±20	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Document number: DS35514 Rev. 3 - 2

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol		Parameter	Min	Max	Unit
V _{CC}	Operating Voltage		0.8	3.6	V
VI	Input Voltage		0	3.6	V
Vo	Output Voltage		0	Vcc	V
		$V_{CC} = 0.8V$		-20	μA
		V _{CC} = 1.1V		-1.1	
l .	High Lavel Output Current	V _{CC} = 1.4V		-1.7	
I _{OH}	High-Level Output Current	V _{CC} = 1.65V		-1.9	mA
		V _{CC} = 2.3V		-3.1	
		V _{CC} = 3.0V		-4	
		V _{CC} = 0.8V		20	μA
		V _{CC} = 1.1V			
	Lave Lavel Outrot Coment	V _{CC} = 1.4V		1.7	
I _{OL}	Low-Level Output Current	V _{CC} = 1.65V		1.9	mA
		V _{CC} = 2.3V		3.1	
		V _{CC} = 3.0V		4	
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 0.8V to 3.6V		200	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note:

5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vcc	T _A = -	+25°C	T _A = -40	to +85°C	Unit
Syllibol	Parameter	rest Conditions		Min	Max	Min	Max	Unit
			0.8V to 1.65V	0.80 X V _{CC}		0.80 X V _{CC}		
ViH	High-Level Input		1.65V to 1.95V	0.65 X V _{CC}		0.65 X V _{CC}		V
VIH	Voltage		2.3V to 2.7V	1.6		1.6		v
			3.0V to 3.6V	2.0		2.0		
			0.8V to 1.65V		0.30 X V _{CC}		0.30 X V _{CC}	
V_{IL}	Low-Level Input		1.65V to 1.95V		0.35 X V _{CC}		0.35 X V _{CC}	V
* 12	Voltage		2.3V to 2.7V		0.7		0.7	-
			3.0V to 3.6V	., .,	0.9		0.9	
		I _{OH} = -20μA	0.8V to 3.6V	V _{CC} – 0.1		V _{CC} – 0.1		
		I _{OH} = -1.1mA	1.1V	0.75 X V _{CC}		0.7 X V _{CC}		
	High-Level Output Voltage	I _{OH} = -1.7mA	1.4V	1.11		1.03		
V _{OH}		$I_{OH} = -1.9 \text{mA}$	1.65V	1.32		1.3		V
VOH		I _{OH} = -2.3mA	2.3V	2.05		1.97		v
		I _{OH} = -3.1mA	2.3V	1.9		1.85		
		I _{OH} = -2.7mA	0) /	2.72		2.67		
		I _{OH} = -4mA	3V	2.6		2.55		
		I _{OL} = 20μA	0.8V to 3.6V		0.1		0.1	
		I _{OL} = 1.1mA	1.1V		0.3 X V _{CC}		0.3 X V _{CC}	
		I _{OL} = 1.7mA	1.4V		0.31		0.37	
	Low-Level Input	I _{OL} = 1.9mA	1.65V		0.31		0.35	
V_{OL}	Voltage	I _{OL} = 2.3mA			0.31		0.33	V
		I _{OL} = 3.1mA	2.3V		0.44		0.45	
		I _{OL} = 2.7mA			0.31		0.33	
		I _{OL} = 4mA	3V		0.44		0.45	
		A or B Input			0.44			
II	Input Current	V_1 = GND to 3.6V	0V to 3.6V		± 0.1		± 0.5	μA
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V		± 0.2		± 0.6	μA
Δl _{OFF}	Delta Power Down Leakage Current	V_I or $V_O = 0V$ to 3.6V	0V to 0.2V		± 0.2		± 0.6	μА
Icc	Supply Current	$V_I = GND \text{ or } V_{CC},$ $I_O = 0$	0.8V to 3.6V		0.5		0.9	μΑ
ΔI _{CC}	Additional Supply Current	One input at V_{CC} –0.6V Other input at V_{CC} or GND	3.3V		40		50	μА



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	T _A = -40	to +125°C	Unit
Symbol	Parameter	rest Conditions	V _{CC}	Min	Max	Unit
		_	0.8V to 1.65V	0.80 X V _{CC}	_	
	High-Level Input Voltage	_	1.65V to 1.95V	0.70 X V _{CC}	_	V
V _{IH}	Trigit-Level input voltage	_	2.3V to 2.7V	1.6	_	
		_	3.0V to 3.6V	2.0	_	
		_	0.8V to 1.65V	<u> </u>	0.25 X V _{CC}	
VIL	Low-Level Input Voltage	_	1.65V to 1.95V	_	0.30 X V _{CC}	V
V IL	Low-Level input voltage	_	2.3V to 2.7V	_	0.7	
		_	3.0V to 3.6V	_	0.9	
		$I_{OH} = -20 \mu A$	0.8V to 3.6V	V _{CC} – 0.11	_	
		$I_{OH} = -1.1 \text{mA}$	1.1V	0.6 X V _{CC}	_	
		$I_{OH} = -1.7 \text{mA}$	1.4V	0.93	_	
.,	High Level Output Voltage	I _{OH} = -1.9mA	1.65V	1.17	_	.,
V _{OH}	High Level Output Voltage	I _{OH} = -2.3mA		1.77	_	V
		I _{OH} = -3.1mA	2.3V	1.67	_	
		I _{OH} = -2.7mA	0) /	2.40	_	
		I _{OH} = -4mA	3V	2.30	_	
		I _{OL} = 20μA	0.8V to 3.6V	_	0.11	
		I _{OL} = 1.1mA	1.1V	_	0.33 X V _{CC}	
		I _{OL} = 1.7mA	1.4V	_	0.41	
.,	Lave Lavel Indust Mallana	I _{OL} = 1.9mA	1.65V	_	0.39	.,
V_{OL}	Low-Level Input Voltage	I _{OL} = 2.3mA	0.01/	_	0.36	V
		I _{OL} = 3.1mA	2.3V	_	0.50	
		I _{OL} = 2.7mA		_	0.36	
		I _{OL} = 4mA	3V	_	0.50	
II	Input Current	A or B Input V _I = GND to 3.6V	0V to 3.6V	_	± 0.75	μA
l _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V	_	± 1.0	μΑ
Δl _{OFF}	Delta Power Down Leakage Current	V_1 or $V_0 = 0V$ to 3.6V	0V to 0.2V	_	± 2.5	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	0.8V to 3.6V	_	1.4	μA
Δlcc	Additional Supply Current	Input at V _{CC} –0.6V Other input at V _{CC} or GND	3.3V	_	75	μА

Operating and Package Characteristics

 $T_A = +25^{\circ}C$

P	arameter	Test Conditions	Vcc	Тур	Unit
			0.8V	5.1	
			1.2V ± 0.1V	5.2	
0	Power dissipation capacitance	f = 1MHz	1.5V ± 0.1V	5.2	
Cpd		No Load	1.8V ± 0.15V	5.5	pF
			2.5V ± 0.2V	5.7	
			3.3V ± 0.3V	6.0	
Cı	Input Capacitance	V _i = V _{CC} or GND	0V or 3.3V	2.0	pF
Co	Output Capacitance	V _O = V _{CC} or GND	0V	2.0	pF



Switching Characteristics

 C_L = 5pF see Figure 1

Parameter	From	TO OUTPUT	V _{CC}		T _A = +25°C		T _A = -40 to +85°C		T _A = -40 to +125°C		Unit
Input	Input		V CC	Min	Тур	Max	Min	Max	Min	Max	Oiiit
			0.8V	-	14.9	1	_	_	_	_	
		Y	1.2V ± 0.1V	2.6	4.7	10.1	2.0	11.1	2.0	12.2	
	Α		1.5V ± 0.1V	2.1	3.4	5.7	1.6	6.5	1.6	7.2]
t _{pd}	A		1.8V ± 0.15V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	ns
			2.5V ± 0.2V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	
			3.3V ± 0.3V	1.4	2.1	3.2	1.0	3.8	1.0	4.2	

C_L = 10pF see Figure 1

Parameter	From	то	V		T _A = +25°C		T _A = -40 to +85°C		T _A = -40 to +125°C		Unit
Input	OUTPUT	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Ullit	
			V8.0	_	18.4	_	_	_	_	_	
			1.2V ± 0.1V	3.2	5.6	11.8	2.3	12.8	2.3	13.5	ns
4	۸		1.5V ± 0.1V	2.6	4.1	6.7	1.9	7.7	1.9	8.5	
t _{pd}	Α	Ţ	1.8V ± 0.15V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	
		2.5V ± 0.2V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	1	
			3.3V ± 0.3V	1.7	2.6	3.8	1.4	4.6	1.4	5.1	

C_L = 15pF see Figure 1

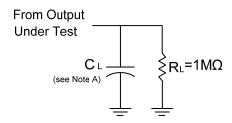
Parameter From	то	- Vcc		T _A = +25°C		$T_A = -40 \text{ to } +85^{\circ}\text{C}$		T _A = -40 to +125°C		Unit	
Parameter	Input OUTPUT		Min	Тур	Max	Min	Max	Min	Max	Unit	
			0.8V	_	21.9	_	_	_	_	_	
		1.2V ± 0.1V	3.6	6.4	13.8	2.6	15.7	2.6	15.9		
	^	V	1.5V ± 0.1V	3.0	4.6	7.6	2.2	8.9	2.2	9.8	1
t _{pd}	Α	Y	1.8V ± 0.15V	2.6	3.9	6.0	2.0	7.2	2.0	7.9	ns
		2.5V ± 0.2V	2.3	3.3	4.8	1.8	5.7	1.8	6.3		
			3.3V ± 0.3V	1.8	3.1	4.2	1.6	5.0	1.6	5.5	1

C_L = 30pF see Figure 1

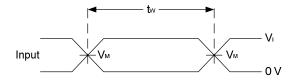
Parameter From		то	V		T _A = +25°C		T _A = -40 to +85°C		T _A = -40 to +125°C		Unit
Parameter	Input OUTPUT	OUTPUT	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Ullit
			V8.0	_	32.1	_	_	_	_	_	
			1.2V ± 0.1V	4.8	8.7	16.3	3.6	18.9	3.6	20.8	ns
	^	V	1.5V ± 0.1V	4.0	6.2	10.3	3.4	12.2	3.4	13.4	
t _{pd}	Α	Ť	1.8V ± 0.15V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	
			2.5V ± 0.2V	2.4	4.4	6.4	2.3	7.7	2.3	8.5	
			3.3V ± 0.3V	2.2	4.2	5.6	2.1	6.5	2.1	7.2	



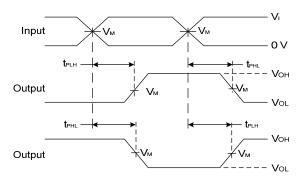
Parameter Measurement Information



V	In	puts	V	C
V _{CC}	V_{l} t_{r}/t_{f} V_{M}		CL	
0.8V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.2V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.5V±0.1V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
1.8V±0.15V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
2.5V±0.2V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF
3.3V±0.3V	V _{CC}	≤3ns	V _{CC} /2	5, 10, 15, 30pF



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

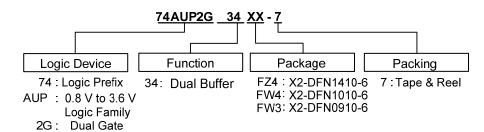
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



Ordering Information



Part Number Package Code	Packaging	7" Tape and Reel		
Part Number	Package Code	(Note 7)	Quantity	Part Number Suffix
74AUP2G34FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7
74AUP2G34FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74AUP2G34FW3-7	FW3	X2-DFN0910-6	5000/Tape & Reel	-7

Note: 7. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)

XX $\frac{XX}{Y}$: Identification Code $\frac{X}{Y}$: Year : 0~9

₩: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal code

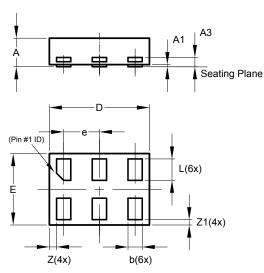
Part Number	Package	Identification Code
74AUP2G34FZ4	X2-DFN1410-6	RT
74AUP2G34FW4	X2-DFN1010-6	ST
74AUP2G34FW3	X2-DFN0910-6	MT



Package Outline Dimensions (All dimensions in mm.)

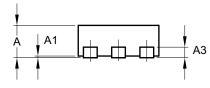
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

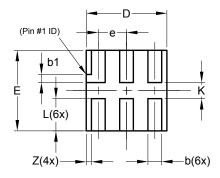
(1) Package Type X2-DFN1410-6



X2-DFN1410-6			
Dim	Min	Max	Тур
Α		0.40	0.39
A1	0.00	0.05	0.02
А3			0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
Е	0.95	1.05	1.00
е	-	-	0.50
L	0.25	0.35	0.30
Z			0.10
Z 1	0.045	0.105	0.075
All Dimensions in mm			

(2) Package Type: X2-DFN1010-6





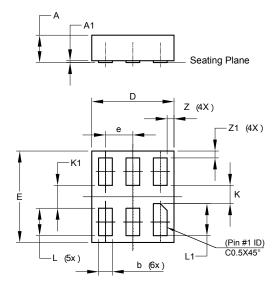
X2-DFN1010-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
A3	_	-	0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
Е	0.95	1.05	1.00
е	_		0.35
L	0.35	0.45	0.40
K	0.15	_	_
Z	_		0.065
All Dimensions in mm			



Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

(3) Package Type: X2-DFN0910-6



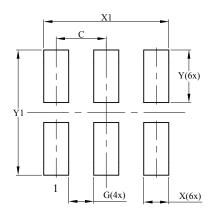
	X2-DFN0910-6		
Dim	Min	Max	Тур
Α	-	0.35	0.30
A1	0	0.03	0.02
b	0.10	0.20	0.15
D	0.85	0.95	0.90
Е	0.95	1.05	1.00
е	-	-	0.30
K	0.20	-	ı
K1	0.25	-	ı
١	0.25	0.35	0.30
L1	0.30	0.40	0.35
Z	-	-	0.075
Z 1	-	-	0.075
All Dimensions in mm			



Suggested Pad Layout

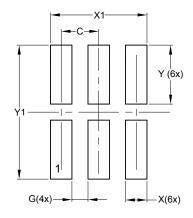
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type X2-DFN1410-6



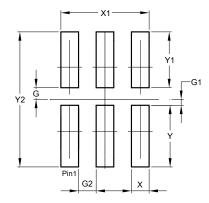
Dimensions	Value (in mm)
С	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

(2) Package Type: X2-DFN1010-6



Dimensions	Value (in mm)
С	0.350
G	0.150
Х	0.200
X1	0.900
Y	0.550
Y1	1.250

(3) Package Type: X2-DFN0910-6



Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
X	0.150
X1	0.750
Y	0.525
Y1	0.475
Y2	1.150



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